

August 1998

54FCT245

Octal Bidirectional Transceiver with TRI-STATE® Outputs

General Description

The 'FCT245 contains eight non-inverting bidirectional buffers with TRI-STATE outputs and is intended for bus-oriented applications. Current sinking capability is 48 mA on both the A and B ports. The Transmit/Receive (T/\overline{R}) input determines the direction of data flow through the bidirectional transceiver. Transmit (active HIGH) enables data from A ports to B ports; Receive (active LOW) enables data from B ports to A ports. The Output Enable input, when HIGH, disables both A and B ports by placing them in a High Z condition.

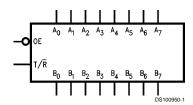
Features

- TTL input and output level compatible
- A and B output sink capability of 48 mA, source capability of 12 mA
- CMOS power consumption
- Standard Microcircuit Drawing (SMD) 5962-8762901

Ordering Code:

Military	Package	Package Description		
	Number			
54FCT245DMQB	J20A	20-Lead Ceramic Dual-In-Line		
54FCT245FMQB	W20A	20-Lead Cerpak		
54FCT245LMQB	E20A	20-Lead Ceramic Leadless Chip Carrier, Type C		
	54FCT245DMQB 54FCT245FMQB	Number 54FCT245DMQB J20A 54FCT245FMQB W20A		

Logic Symbol



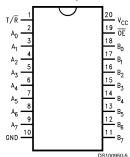
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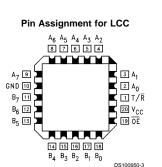
DS100950

Connection Diagrams

Pin Assignment for DIP and Flatpak.



Pin Assignment for LCC



Pin Descriptions

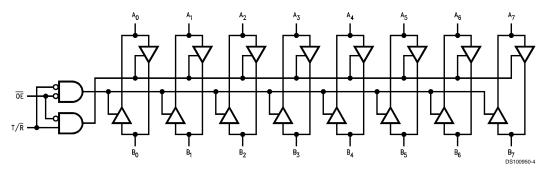
Pin Names	Description			
ŌĒ	Output Enable Input (Active LOW)			
T/R	Transmit/Receive Input			
A ₀ -A ₇ B ₀ -B ₇	Side A Inputs or TRI-STATE Outputs			
B ₀ -B ₇	Side B Inputs or TRI-STATE Outputs			

Truth Table

Inp	outs	Output		
ŌĒ	T/R			
L	L	Bus B Data to Bus A		
L	Н	Bus A Data to Bus B		
Н	X	High Z State		

H = HIGH Voltage Level L = LOW Voltage Level X = Immaterial

Logic Diagram



Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Storage Temperature -65°C to $+150^{\circ}\text{C}$ Ambient Temperature under Bias -55°C to $+125^{\circ}\text{C}$

Junction Temperature under Bias

Ceramic -55°C to +175°C

 $\ensuremath{\text{V}_{\text{CC}}}$ Pin Potential to

Ground Pin -0.5V to +7.0V

Input Voltage (Note 2) -0.5V to +7.0V Input Current (Note 2) -30 mA to +5.0 mA

Voltage Applied to Any Output

in the Disabled or

Power-off State -0.5V to 5.5V

% in the HIGH State $$-0.5\rm{V} to \rm{V}_{CC} Current Applied to Output in LOW State (Max) twice the rated I_{OL} (mA)

Recommended Operating Conditions

Free Air Ambient Temperature

Military –55°C to +125°C

Supply Voltage

Military +4.5V to +5.5V

Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

DC Electrical Characteristics

Symbol	Parameter		FCT245		l lade		Conditions	
			Min	Max	Units	V _{cc}		
V _{IH}	Input HIGH Voltage		2.0		V		Recognized HIGH Signal	
V _{IL}	Input LOW Voltage			0.8	V		Recognized LOW Signal	
V _{CD}	Input Clamp Did	ode Voltage		-1.2	V	Min	$I_{IN} = -18 \text{ mA } (\overline{OE}, T/\overline{R})$	
V _{OH}	Output HIGH	54FCT	4.3		V	Min	$I_{OH} = -300 \text{ uA } (A_n, B_n)$	
	Voltage	54FCT	2.4		V	Min	$I_{OH} = -12 \text{ mA } (A_n, B_n)$	
V _{OL}	Output LOW	54FCT		0.2	V	Min	$I_{OL} = 300 \text{ uA } (A_n, B_n)$	
	Voltage	54FCT		0.55	V	Min	$I_{OL} = 48 \text{ mA } (A_n, B_n)$	
I _{IH}	Input HIGH Cur	rent		5			$V_{IN} = 2.7V (\overline{OE}, T/\overline{R})$	
				5	μA	Max	$V_{IN} = V_{CC} (\overline{OE}, T/\overline{R})$	
I _{BVIT}	Input HIGH Current Breakdown Test (I/O)			20	μΑ	Max	$V_{IN} = 5.5V (A_n, B_n)$	
I _{IL}	Input LOW Curi	rent		-5	μA	Max	$V_{IN} = 0.0V (\overline{OE}, T/\overline{R})$	
I _{os}	Output Short-Circuit Current			-60	mA	Max	$V_{OUT} = 0.0V (A_n, B_n)$	
I _{CCQ}	Power Supply Current			1.5	mA	Max	V_{IN} = 0.2V or V_{IN} = 5.3V, V_{CC} = 5.5V	
ΔI_{CC}	Power Supply C	Current		2.0	mA	Max	$V_{CC} = 5.5V, V_{IN} = 3.4V$	
I _{CCT}	I _{CCT} Total Power Supply Current			6.0	mA		$V_{\rm IN}$ = 3.4V or $V_{\rm IN}$ = GND, $\overline{\rm OE}$ = T/ $\overline{\rm R}$ = GND, $V_{\rm CC}$ = 5.5V, f _I = 10Mhz, outputs open, one bit toggling - 50% duty cycle	
				5.5	mA	Max	$V_{\rm IN}$ = 5.3V or $V_{\rm IN}$ = 0.2V, $\overline{\rm OE}$ = T/R = GND, $V_{\rm CC}$ = 5.5V, f _I = 10Mhz, outputs open, one bit toggling - 50% duty cycle	
I _{CCD}	Dynamic I _{CC} (Note 3)			0.4	mA/ MHz	Max	Outputs Open, $\overline{\text{OE}}$ =GND, $\text{T/}\overline{\text{R}}$ = GND or V_{CC} One Bit Toggling, 50% Duty Cycle	

Note 3: Guaranteed but not tested.

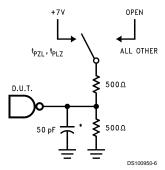
Symbol	Parameter	541	FCT	Units	Fig. No.
		T _A = -55°(C to +125°C		
		V _{CC} = 4.5V-5.5V			
		C _L =	50 pF	1	
		Min	Max	1	
t _{PLH}	Propagation Delay	1.5	7.5	ns	Figure 4
t _{PHL}	Data to Outputs	1.5	7.5		
t _{PZH}	Output Enable	1.5	10.0	ns	Figure 5
t _{PZL}	Time	1.5	10.0		
t _{PHZ}	Output Disable	1.5	10.0	ns	Figure 5
t _{PLZ}	Time	1.5	10.0		

Capacitance

Symbol	Parameter	Max	Units	Conditions	
				T _A = 25°C	
C _{IN}	Input Capacitance	10.0	pF	$V_{CC} = 0V (\overline{OE}, T/\overline{R})$	
C _{I/O} (Note 4)	I/O Capacitance	12.0	pF	$V_{CC} = 5.0V (A_n, B_n)$	

Note 4: $C_{I/O}$ is measured at frequency f = 1 MHz, per MIL-STD-883B, Method 3012.

AC Loading



*Includes jig and probe capacitance

FIGURE 1. Standard AC Test Load

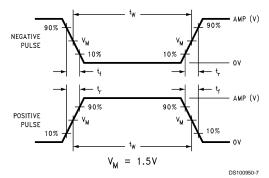


FIGURE 2. Test Input Signal Levels

Amplitude	Rep. Rate	t _w	t _r	t _f	
3.0V	1 MHz	500 ns	2.5 ns	2.5 ns	

FIGURE 3. Test Input Signal Requirements

AC Waveforms

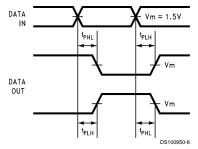


FIGURE 4. Propagation Delay Waveforms for Inverting and Non-Inverting Functions

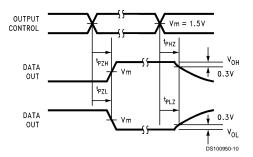
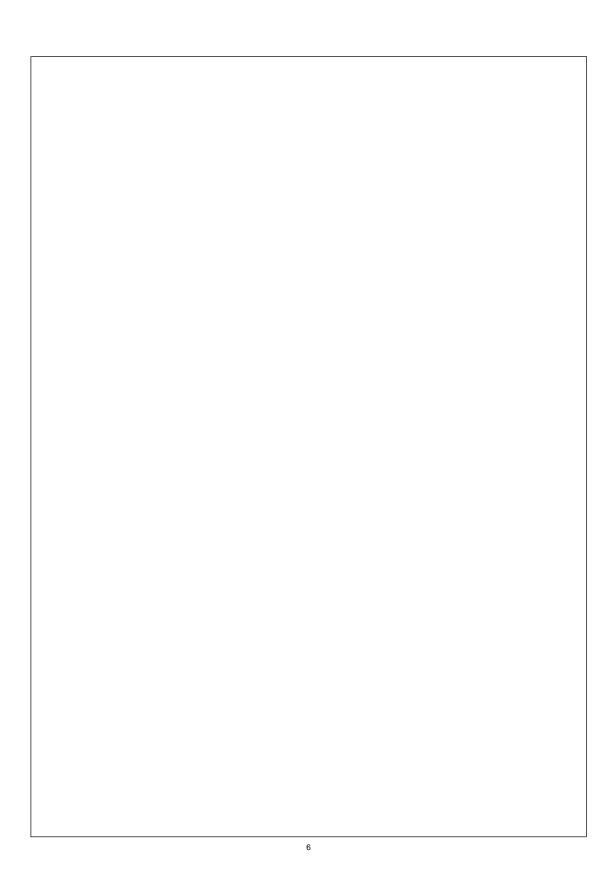
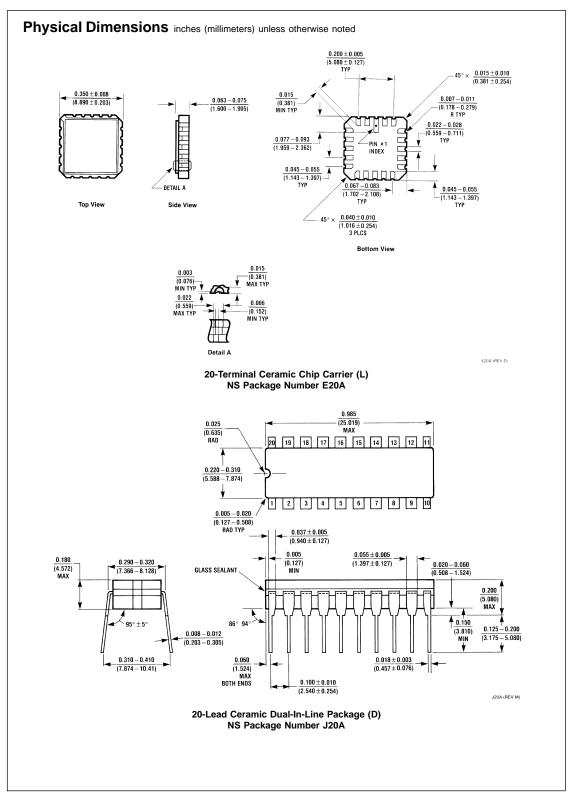
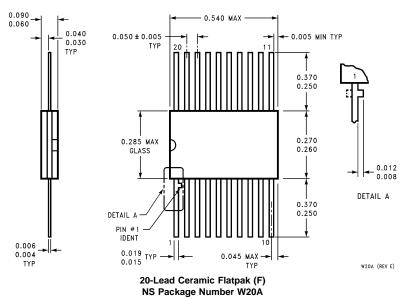


FIGURE 5. TRI-STATE Output HIGH and LOW Enable and Disable Times





Physical Dimensions inches (millimeters) unless otherwise noted (Continued)



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